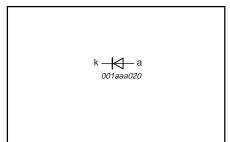
# Rectifier diodes ultrafast

**BYR29** series

## **FEATURES**

- · Low forward volt drop
- · Fast switching
- · Soft recovery characteristic
- · Reverse surge capability
- · High thermal cycling performance
- · Low thermal resistance

## **SYMBOL**



## **QUICK REFERENCE DATA**

$$V_R = 500 \text{ V/ } 600 \text{ V/ } 700 \text{ V / } 800 \text{ V}$$

$$V_F \le 1.5 \text{ V}$$

$$I_{F(AV)} = 8 \text{ A}$$

$$t_{rr} \le 75 \text{ ns}$$

#### **GENERAL DESCRIPTION**

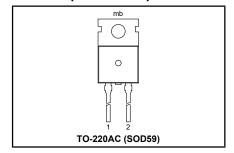
Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYR29 series is supplied in the conventional leaded SOD59 (TO220AC) package.

#### **PINNING**

DESCRIPTION		
cathode		
anode		
cathode		

# SOD59 (TO220AC)



## **LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.		MA	AX.		UNIT
		BYR29		-500	-600	-700	-800	
$V_{RRM}$	Peak repetitive reverse voltage		-	500	600	700	800	V
V <sub>RWM</sub>	Crest working reverse voltage		-	500	600	700	800	V
V <sub>R</sub>	Continuous reverse voltage		-	500	600	700	800	V
I <sub>F(AV)</sub>	Average forward current <sup>1</sup>	square wave; $\delta = 0.5$ ;	-		8	3		Α
		T <sub>mb</sub> ≤ 115 °C						
I <sub>FRM</sub>	Repetitive peak forward current	t = 25 μs; δ = 0.5;  T <sub>mb</sub> ≤ 115 °C	-		1	6		Α
I <sub>FSM</sub>	Non-repetitive peak forward	t = 10 ms	-		6	0		Α
T GIVI	current	t = 8.3 ms	-		6	6		Α
		sinusoidal; with						
_		reapplied $V_{RRM(max)}$	40					
_stg	Storage temperature		-40			50		,C
$ T_{i} $	Operating junction temperature		-		15	50		°C

#### THERMAL RESISTANCES

THE RIMAL REGIOTATOES						
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-mb</sub>	Thermal resistance junction to mounting base		-	-	2.5	K/W
R <sub>th j-a</sub>		in free air.	-	60	-	K/W

<sup>1</sup> Neglecting switching and reverse current losses

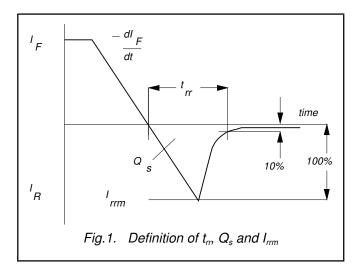
Rectifier diodes ultrafast

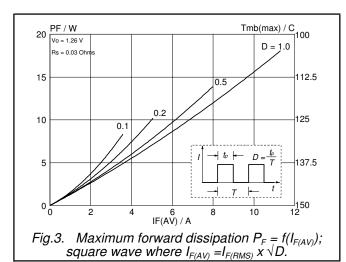
BYR29 series

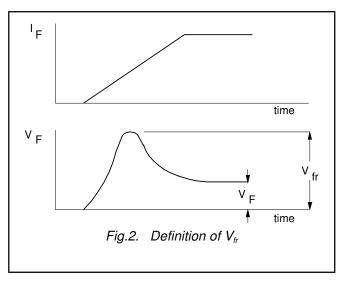
## **ELECTRICAL CHARACTERISTICS**

 $T_i = 25$  °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{F}$	Forward voltage	$I_F = 8 \text{ A}; T_j = 150^{\circ}\text{C}$	-	1.07	1.50	V
I <sub>R</sub>	Reverse current	$I_F = 20 \text{ A}$ $V_R = V_{RRM}$	-	1.75 1.0	1.95 10	μA
$Q_s$	Reverse recovery charge	$V_{R} = V_{RRM}$ ; $T_{j} = 100 ^{\circ}C$ $I_{E} = 2 ^{\circ}A ^{\circ}to ^{\circ}V_{R} \geq 30 ^{\circ}V$ ;	-	0.1 150	0.2 200	mA nC
t <sub>rr</sub>	Reverse recovery time	$dI_F/dt = 20 \text{ A}/\mu\text{s}$ $I_F = 1 \text{ A to } V_R \ge 30 \text{ V};$	-	60	75	ns
I <sub>rrm</sub>	Peak reverse recovery current	$dI_F/dt = 100 \text{ A/}\mu\text{s}$ $I_F = 10 \text{ A to } V_R \ge 30 \text{ V};$	-	-	6	Α
$V_{fr}$	Forward recovery voltage	$dI_F/dt = 50 \text{ A/$\mu$s; T}_i = 100 \text{ °C}$ $I_F = 10 \text{ A; } dI_F/dt = 10 \text{ A/$\mu$s}$	-	5.0	-	V







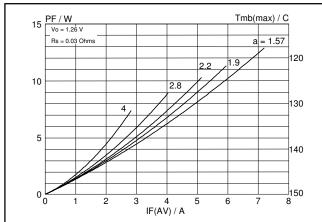
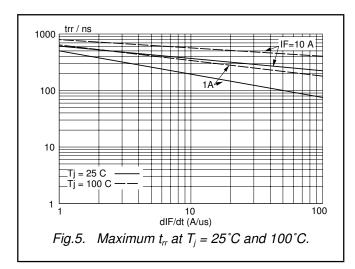


Fig.4. Maximum forward dissipation  $P_F = f(I_{F(AV)})$ ; sinusoidal current waveform where a = form factor =  $I_{F(RMS)} / I_{F(AV)}$ .

WeEn Semiconductors Product specification

# Rectifier diodes ultrafast

BYR29 series



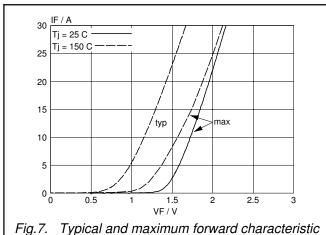
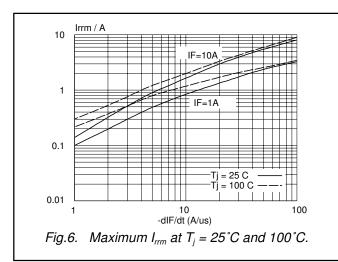
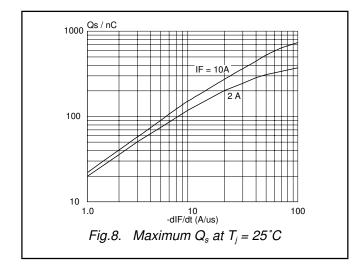
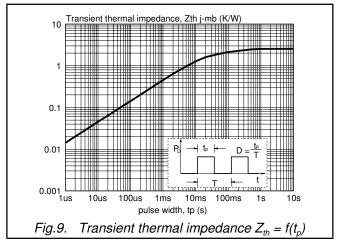


Fig.7. Typical and maximum forward characteristic  $I_F = f(V_F)$ ; parameter  $T_j$ 



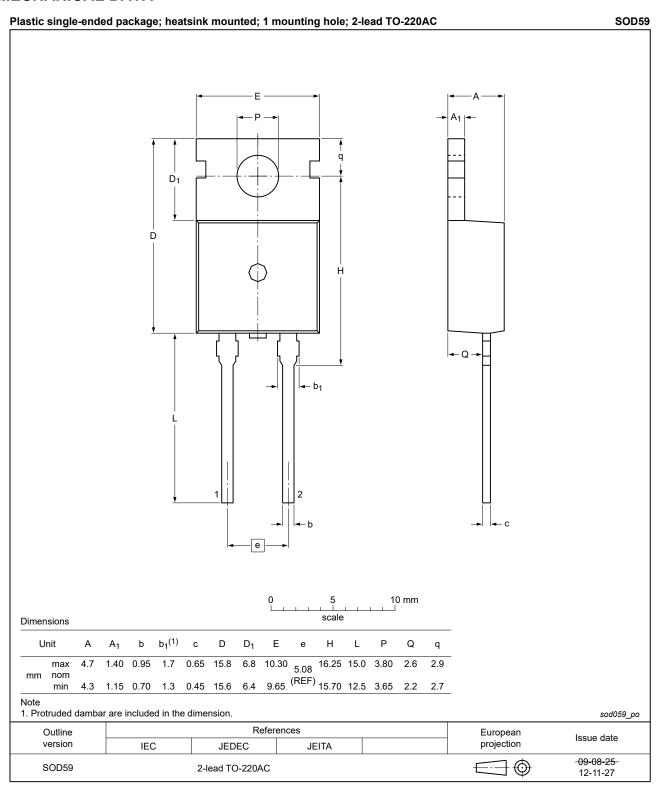




Rectifier diodes ultrafast

BYR29 series

## **MECHANICAL DATA**



## Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.ween-semi.com">http://www.ween-semi.com</a>.

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